

KB-2965EGW-B

HIGH EFFICIENCY RED
GREEN

Features

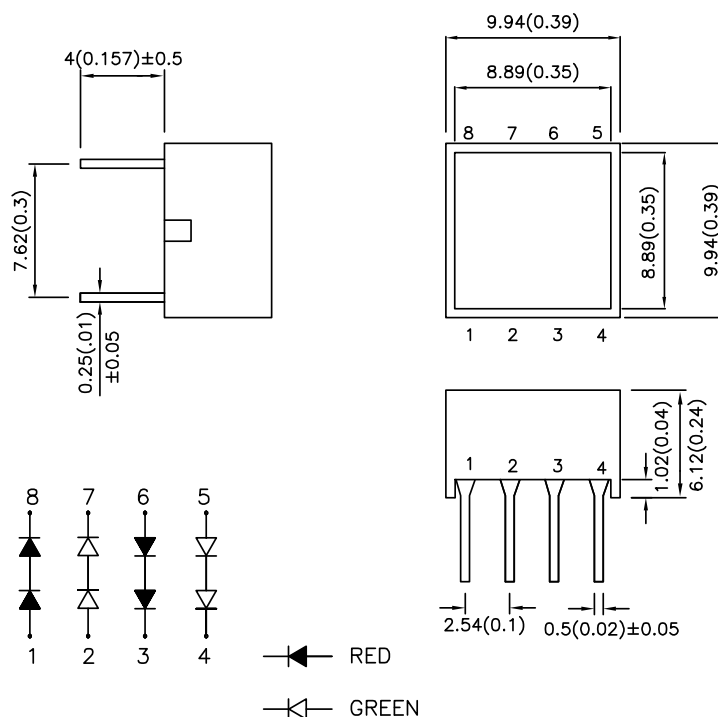
- UNIFORM LIGHT EMITTING AREA.
- LOW CURRENT OPERATION.
- EASILY MOUNTED ON P.C. BOARDS.
- FLUSH MOUNTABLE.
- EXCELLENT ON/OFF CONTRAST.
- CAN BE USED WITH PANELS AND LEGEND MOUNTS.

Description

The High Efficiency Red source color devices are made With Gallium Arsenide Phosphide on Gallium Phosphide Orange Light Emitting Diode.

The Green source color devices are made with Gallium Phosphide Green Light Emitting Diode.

Package Dimensions & Internal Circuit Diagram



Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is ±0.25(0.01") unless otherwise noted.
3. Lead spacing is measured where the lead emerge package.
4. Specifications are subject to change without notice.

Selection Guide

Part No.	Dice	Lens Type	Iv (mcd) @ 20mA	
			Min.	Typ.
KB-2965EGW-B	HIGH EFFICIENCY RED (GaAsP/GaP)	WHITE DIFFUSED	50	120
	GREEN (GaP)		50	120

Electrical / Optical Characteristics at T_A=25°C

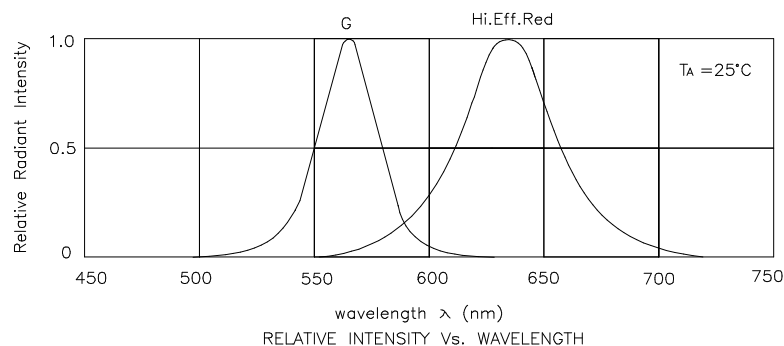
Symbol	Parameter	Device	Typ.	Max.	Units	Test Conditions
λ_{peak}	Peak Wavelength	High Efficiency Red Green	627 565		nm	I _F =20mA
λ_D	Dominate Wavelength	High Efficiency Red Green	625 568		nm	I _F =20mA
$\Delta\lambda_{1/2}$	Spectral Line Half-width	High Efficiency Red Green	45 30		nm	I _F =20mA
C	Capacitance	High Efficiency Red Green	15 15		pF	V _F =0V;f=1MHz
V _F	Forward Voltage	High Efficiency Red Green	4.0 4.4	5.0 5.0	V	I _F =20mA
I _R	Reverse Current	All		10	uA	V _R = 10V

Absolute Maximum Ratings at T_A=25°C

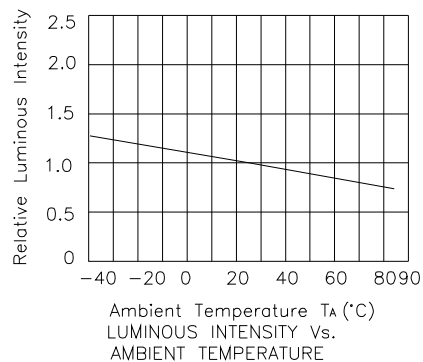
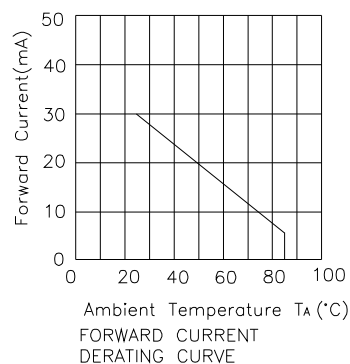
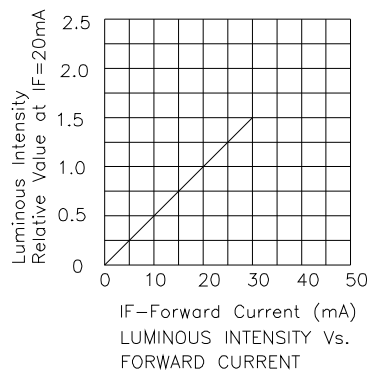
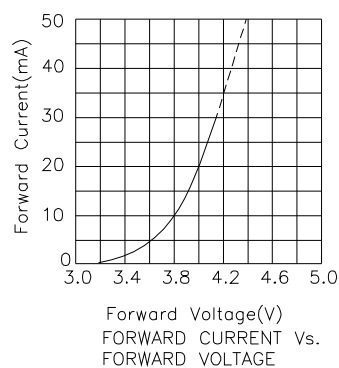
Parameter	High Efficiency Red	Green	Units
Power dissipation	150	125	mW
DC Forward Current	30	25	mA
Peak Forward Current [1]	160	140	mA
Reverse Voltage	10	10	V
Operating/storage Temperature	-40°C To +85°C		
Lead Solder Temperature [2]	260°C For 5 Seconds		

Notes:

1. 1/10 Duty Cycle, 0.1ms Pulse Width.
2. 2mm below package base.



KB-2965EGW-B High Efficiency Red



Green

